
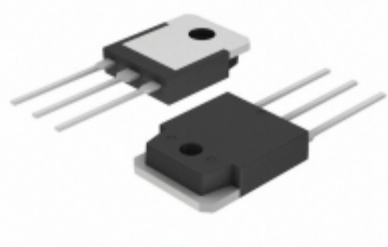

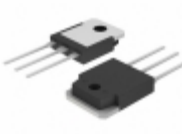



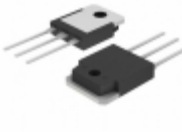
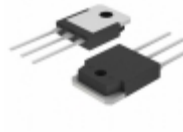

	<h2>FQA19N60</h2>
	<p>Hersteller-Teilenummer: FQA19N60</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 600V 18.5A TO-3P</p> <p>Datenblätter:  FQA19N60.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 14663 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQA19N60
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 600V 18.5A TO-3P
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	14663 pcs Stock
Hersteller Standard Vorlaufzeit	11 Weeks
detaillierte Beschreibung	N-Channel 600V 18.5A (Tc) 300W (Tc) Through Hole
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-3P-3, SC-65-3
Supplier Device-Gehäuse	TO-3PN
Verlustleistung (max)	300W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	18.5A (Tc)
Rds On (Max) @ Id, Vgs	380 mOhm @ 9.3A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	90nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	3600pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	FQA19N60-ND









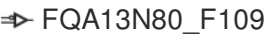








































FQA19N60 ist neu im Original, Suche FQA19N60 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQA19N60 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQA19N60: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQA20N40 Fairchild/ON Semiconductor MOSFET N-CH 400V 19.5A TO-3P</p>	 <p>FQA19N20C Fairchild/ON Semiconductor MOSFET N-CH 200V 21.8A TO-3P</p>	 <p>FQA20N40 AMI Semiconductor / ON Semiconductor MOSFET N-CH 400V 19.5A TO-3P</p>	 <p>FQA19N20L AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 25A TO-3P</p>
 <p>FQA20N50 FSC FQA20N50 FSC</p>	 <p>FQA19N20C AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 21.8A TO-3P</p>	 <p>FQA19N60 Fairchild/ON Semiconductor MOSFET N-CH 600V 18.5A TO-3P</p>	 <p>FQA19N20 #T FSC FQA19N20 #T FSC</p>

heiße Teile

Mehr

 FQA12P20	 FQA13N50	 FQA13N50	 D FQA13N50C	 FQA13N50C
 FQA13N50C_F109	 FQA13N80	 D FQA13N80	 FQA13N80_F109	 FQA140N10
 FQA140N10	 FQA14N30	 FQA14N30	 FQA160N08	 FQA160N08
 D FQA16N50	 FQA16N50	 FQA170N06	 FQA170N06	 FQA18N40
 FQA18N50	 FQA19N20C	 FQA19N20C	 FQA19N20L	 FQA19N20L
 FQA19N60	 FQA20N40	 D FQA20N40	 FQA20N50	 FQA20N60
 FQA20N80	 D FQA24N50	 FQA24N50	 FQA24N50F	 FQA24N50F
 FQA24N60	 FQA24N60	 FQA27N25	 FQA27N25	 FQA28N15
 FQA28N15	 FQA28N15_F109	 FQA28N15_F109	 D FQA28N50	 FQA28N50
 FQA28N50F	 FQA28N50F	 FQA30N40	 FQA30N40	 FQA32N20C

Contact us: Info@Y-IC.com

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